NSN 5961-01-413-1084

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Inclosure Material:

Ceramic

Voltage Rating In Volts Per Characteristic:

32.0 working peak reverse voltage, peak total value

Power Rating Per Characteristic:

10.0 watts any acceptable preset

Special Features:

Peak pulse power dissipation at 25 degrees c., 15,000 w at 1 ms; maximum clamping v at 1 pp, 45 v; operating and storage temp -65 to

150 deg. C

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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